

PMV20XNE 30 V, N-channel Trench MOSFET 10 November 2014

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- Enhanced power dissipation capability of 1200 mW
- ElectroStatic Discharge (ESD) protection: 2 kV HBM

3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	30	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	7.2	А
Static characteristics						_	
$R_{DSon} \qquad drain-source on-state resistance \qquad V_{GS} = 4.5 V; I_D = 5.7 A; T_j = 25 ^{\circ}C \qquad - 19 \qquad 23 \qquad m\Omega$							

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain	1 2 TO-236AB (SOT23)	G G S S 017aaa255

6. Ordering information

Table 3. Ordering information				
Type number Package				
	Name	Description	Version	
PMV20XNE	TO-236AB	plastic surface-mounted package; 3 leads	SOT23	

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
PMV20XNE	%G9

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5.Limiting values

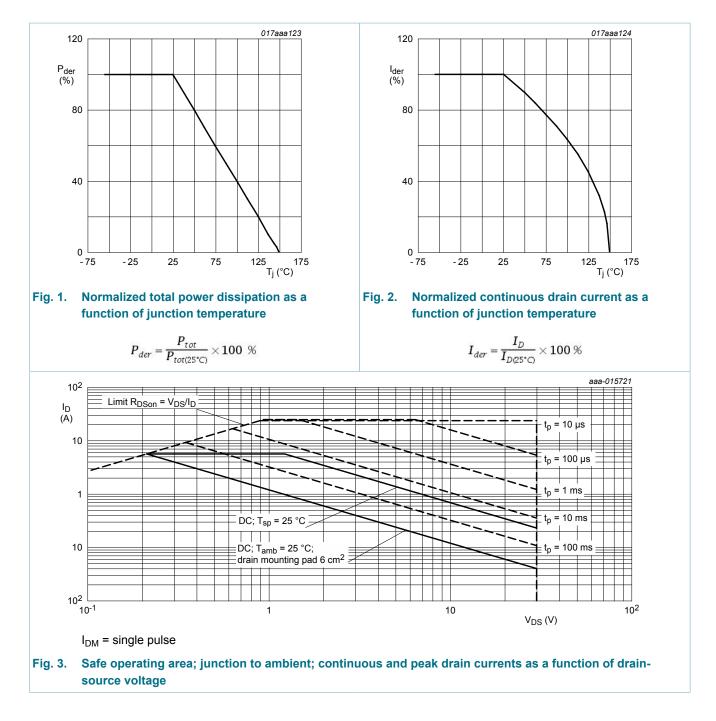
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit	
V _{DS}	drain-source voltage	T _j = 25 °C		-	30	V	
V _{GS}	gate-source voltage			-12	12	V	
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	7.2	А	
		V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	5.7	А	
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	3.6	А	
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	24	А	
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	510	mW	
			[1]	-	1200	mW	
		T _{sp} = 25 °C		-	6940	mW	
Tj	junction temperature			-55	150	°C	
T _{amb}	ambient temperature			-55	150	°C	
T _{stg}	storage temperature			-65	150	°C	
Source-dra	Source-drain diode						
I _S	source current	T _{amb} = 25 °C	[1]	-	1.2	А	

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

30 V, N-channel Trench MOSFET



9. Thermal characteristics

Table 6. T	hermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance	in free air	[1]	-	208	245	K/W	
from junction to ambient			[2]	-	88	104	K/W
		in free air; t ≤ 5 s	[2]	-	55	65	K/W

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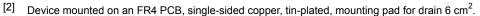
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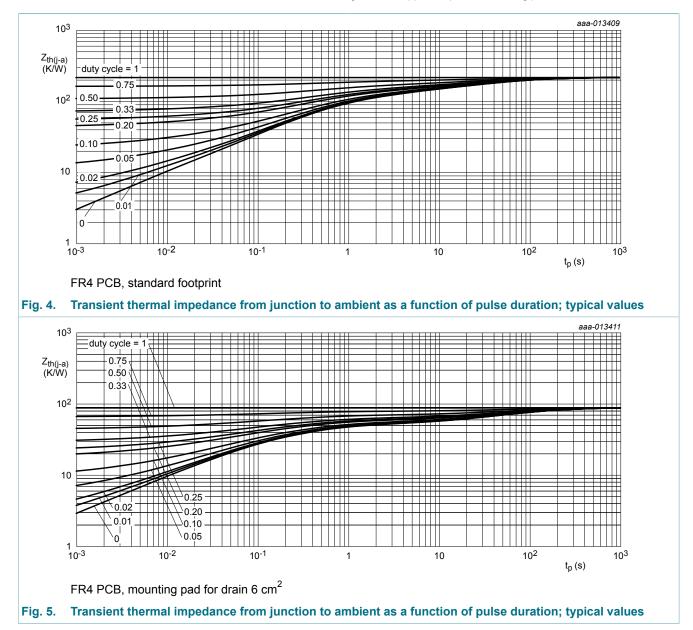
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point		-	13	18	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.





10. Characteristics

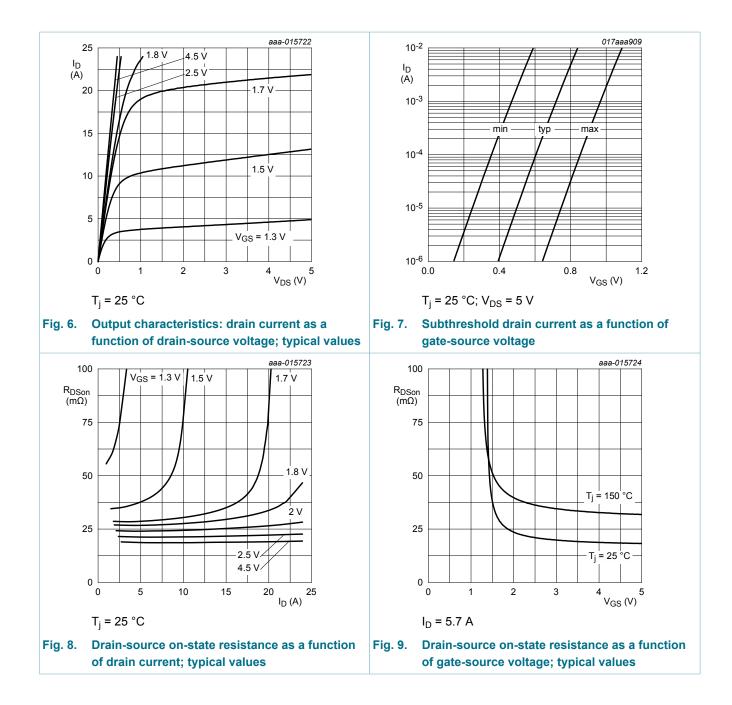
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	0.4	0.65	0.9	V
I _{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
R _{DSon} drain-source on-state resistance	drain-source on-state	V_{GS} = 4.5 V; I _D = 5.7 A; T _j = 25 °C	-	19	23	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 5.7 A; T _j = 150 °C	-	31	37	mΩ
		V _{GS} = 2.5 V; I _D = 5 A; T _j = 25 °C	-	22	30	mΩ
	V _{GS} = 1.8 V; I _D = 1.9 A; T _j = 25 °C	-	27	38	mΩ	
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 2 A; T _j = 25 °C	-	11	-	S
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	-	1.8	-	Ω
Dynamic ch	aracteristics	1	I			
Q _{G(tot)}	total gate charge	V_{DS} = 10 V; I _D = 5 A; V _{GS} = 4.5 V;	-	12.4	18.6	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.2	-	nC
Q _{GD}	gate-drain charge		-	2.1	-	nC
C _{iss}	input capacitance	V _{DS} = 15 V; f = 1 MHz; V _{GS} = 0 V;	-	1150	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	110	-	pF
C _{rss}	reverse transfer capacitance		-	85	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; I _D = 5 A; V_{GS} = 4.5 V;	-	8	-	ns
t _r	rise time	R _{G(ext)} = 6 Ω; T _j = 25 °C	-	17	-	ns
t _{d(off)}	turn-off delay time		-	33	-	ns
t _f	fall time		-	32	-	ns
Source-drai	n diode	· · · · · · · · · · · · · · · · · · ·	1	1		
V _{SD}	source-drain voltage	I _S = 1.2 A; V _{GS} = 0 V; T _i = 25 °C	-	0.7	1.2	V

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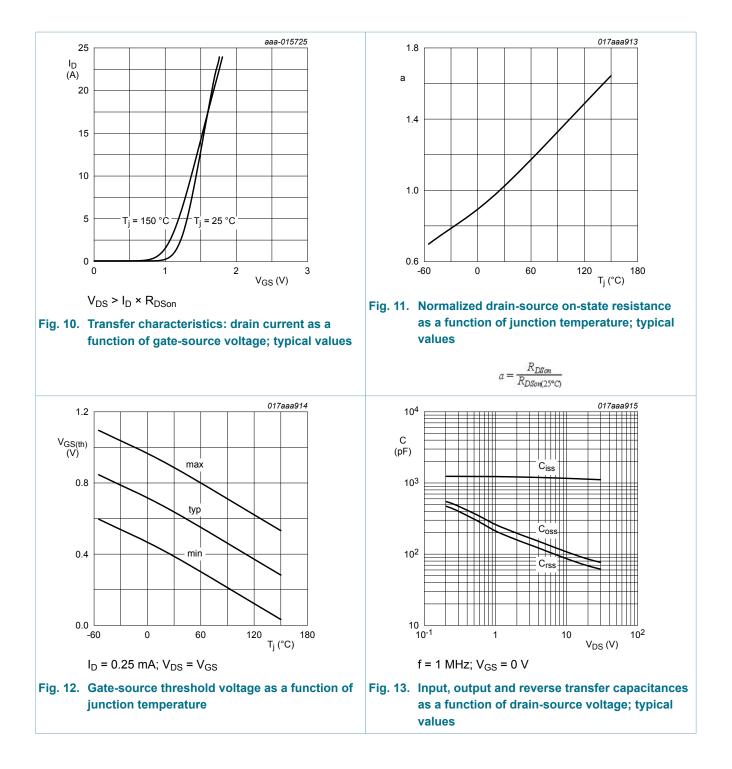
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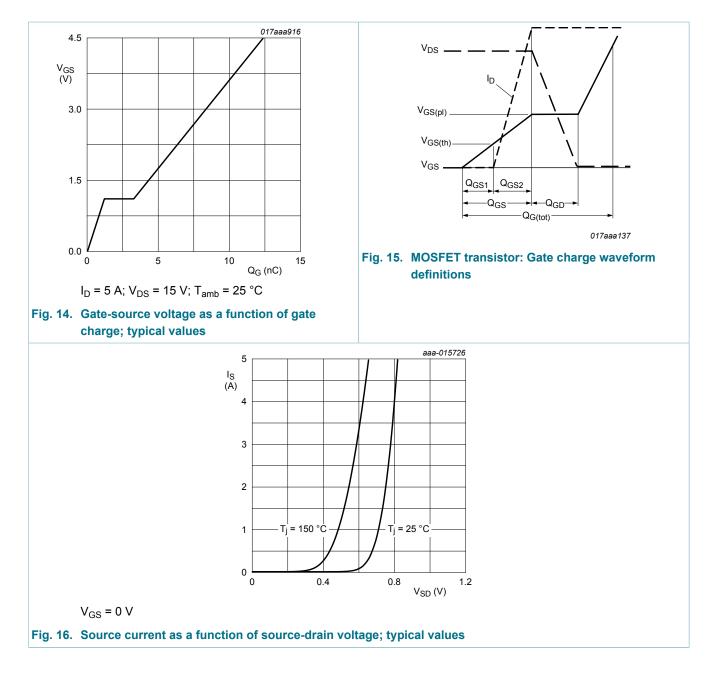
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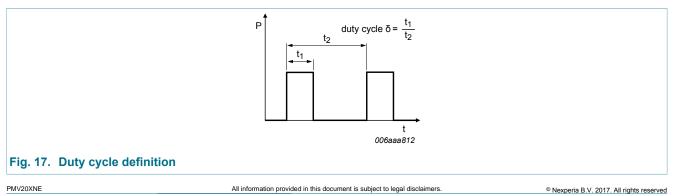
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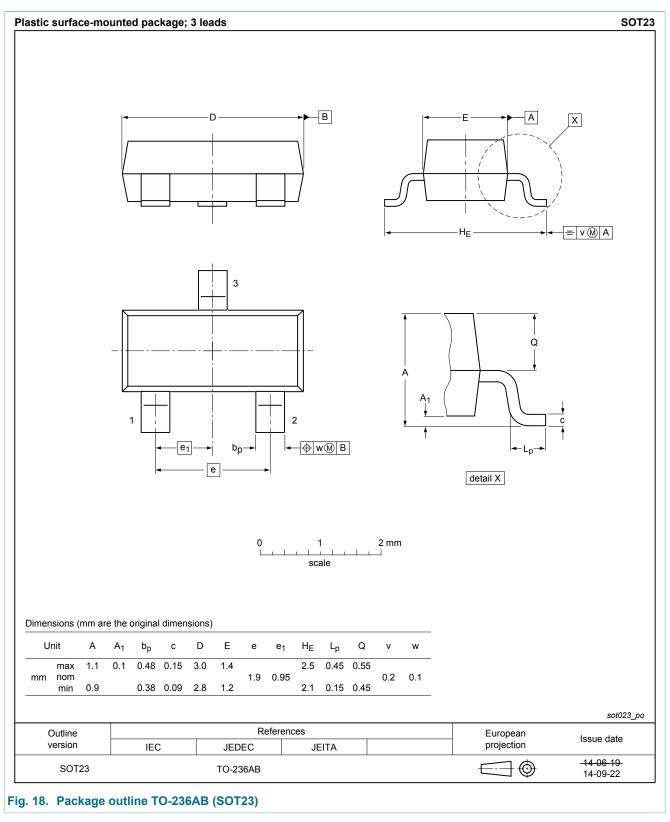
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11. Test information



12. Package outline

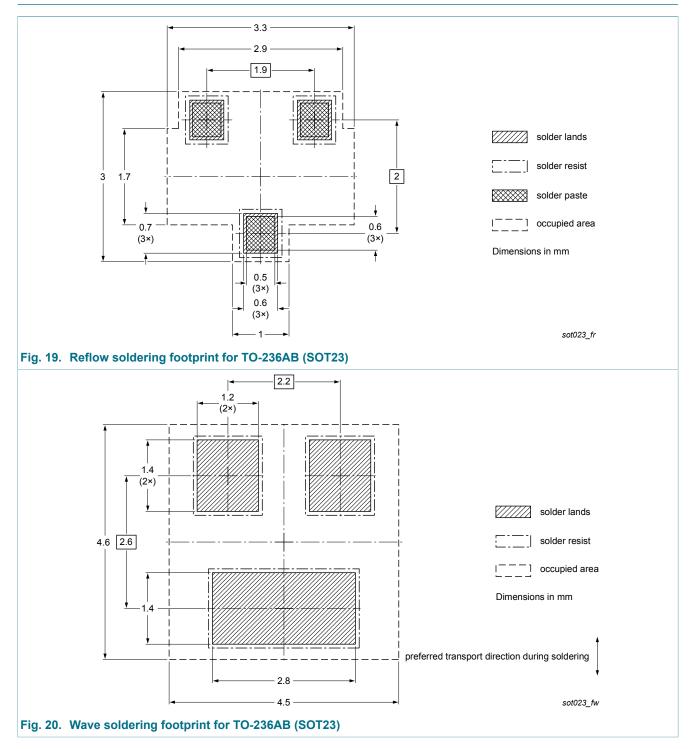


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13. Soldering



14. Revision history

Table 8. Revision history				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMV20XNE v.1	20141110	Product data sheet	-	-

30 V, N-channel Trench MOSFET

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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30 V, N-channel Trench MOSFET

16. Contents

1	General description1
2	Features and benefits1
3	Applications1
4	Quick reference data 1
5	Pinning information2
6	Ordering information2
7	Marking2
8	Limiting values3
9	Thermal characteristics4
10	Characteristics6
11	Test information9
12	Package outline 10
13	Soldering11
14	Revision history12
15	Legal information13
15.1	Data sheet status 13
15.2	Definitions13
15.3	Disclaimers13
15.4	Trademarks 14

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